

**Features**

Interdigitated amplifying gates
Fast turn-on and high di/dt
Low switching losses

Typical Applications

Inductive heating
Electronic welders
Self-commutated inverters

Part No. H100KKM-KT100cT

$I_{T(AV)}$	4300A
V_{DRM}, V_{RRM}	4500V 4800V
	5000V 5200V
t_q	60~150μs

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_J (C)	VALUE			UNIT
				Min	Type	Max	
$I_{T(AV)}$	Mean on-state current	180 half sine wave 50Hz Double side cooled, $T_C=55^\circ\text{C}$	125			4300	A
V_{DRM} V_{RRM}	Repetitive peak off-state voltage Repetitive peak reverse voltage	$t_p=10\text{ms}$	125	4500		5200	V
I_{DRM} I_{RRM}	Repetitive peak current	at V_{DRM} at V_{RRM}	125			500	mA
I_{TSM}	Surge on-state current	10ms half sine wave	125			40	kA
I^2t	I^2t for fusing coordination	$V_R=0.6V_{RRM}$	125			8000	$\text{A}^2\text{s}\cdot 10^3$
V_{TO}	Threshold voltage		125			1.58	V
r_T	On-state slope resistance		125			0.15	mΩ
V_{TM}	Peak on-state voltage	$I_{TM}=2500\text{A}$, $F=70\text{kN}$	25			3.40	V
dv/dt	Critical rate of rise of off-state voltage	$V_{DM}=0.67V_{DRM}$	125			1000	V/μs
di/dt	Critical rate of rise of on-state current	$V_{DM}=67\%V_{DRM}$, to 4000A Gate pulse $t_r \leq 0.5\mu\text{s}$ $I_{GM}=1.5\text{A}$ Single pulse	125			500	A/μs
Q_{rr}	Recovery charge	$I_{TM}=2000\text{A}$, $t_p=4000\mu\text{s}$, $di/dt=-20\text{A}/\mu\text{s}$, $V_R=100\text{V}$	125		5000		μC
t_q	Circuit commutated turn-off time	$I_{TM}=2000\text{A}$, $t_p=4000\mu\text{s}$, $V_R=100\text{V}$ $dv/dt=30\text{V}/\mu\text{s}$, $di/dt=-20\text{A}/\mu\text{s}$	125	60		150	μs
I_{GT}	Gate trigger current	$V_A=12\text{V}$, $I_A=1\text{A}$	25	50		300	mA
V_{GT}	Gate trigger voltage			0.8		3.5	V
I_H	Holding current			20		1000	mA
I_L	Latching current					1000	mA
V_{GD}	Non-trigger gate voltage	$V_{DM}=67\%V_{DRM}$	125			0.25	V
$R_{th(j-c)}$	Thermal resistance Junction to case	At 180° sine double side cooled Clamping force 40 kN				0.005	C /W
$R_{th(c-h)}$	Thermal resistance case to heat sink					0.0015	
F_m	Mounting force			81		108	kN
T_{vj}	Junction temperature			-40		125	C
T_{stg}	Stored temperature			-40		140	C
W_t	Weight				1880		g
Outline	KT100cT						

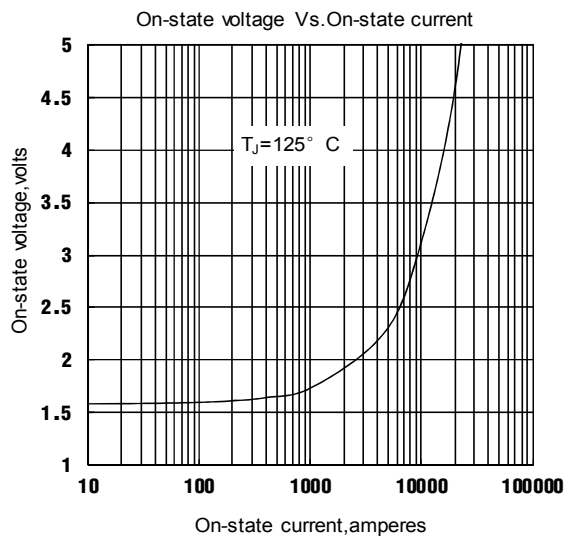


Fig.1

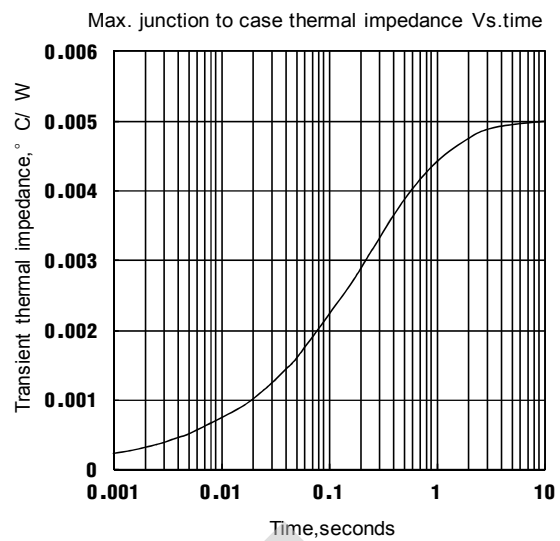


Fig.2

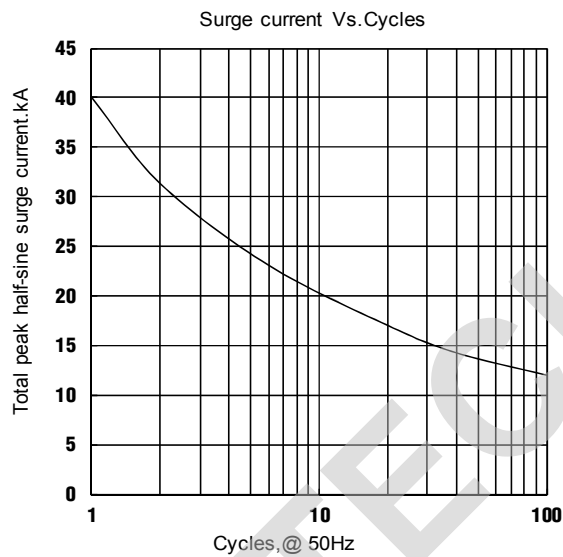


Fig.3

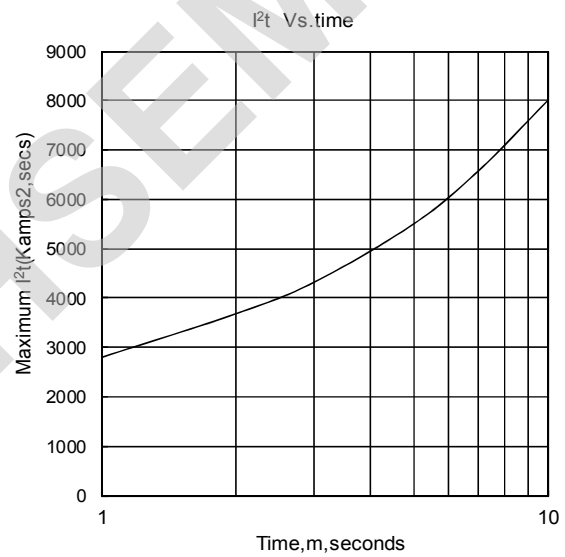


Fig.4

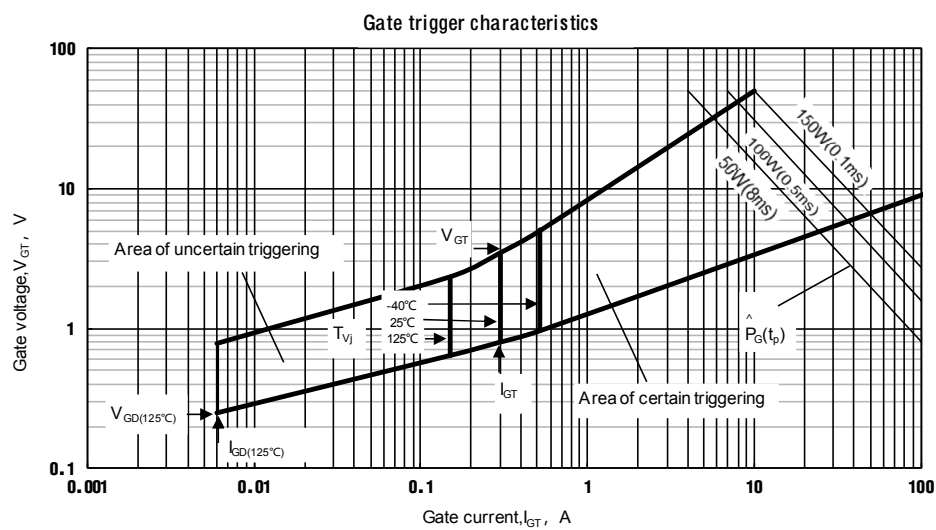
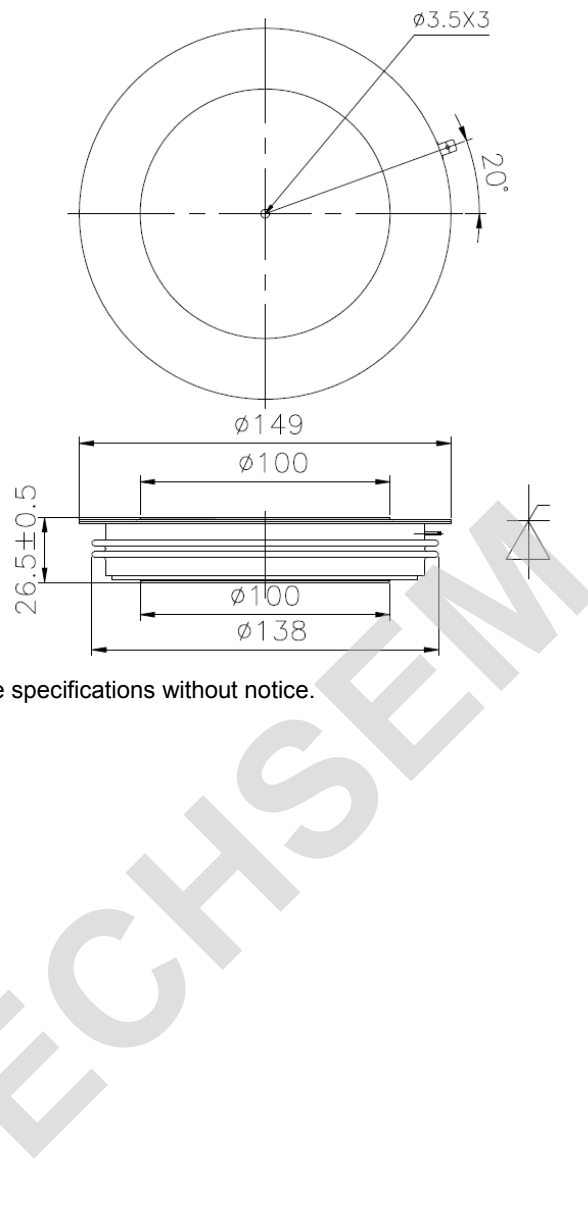


Fig.5

Outline:



TECHSEM reserves the right to change specifications without notice.